Low Emittance 500 kV Thermionic Electron Gun

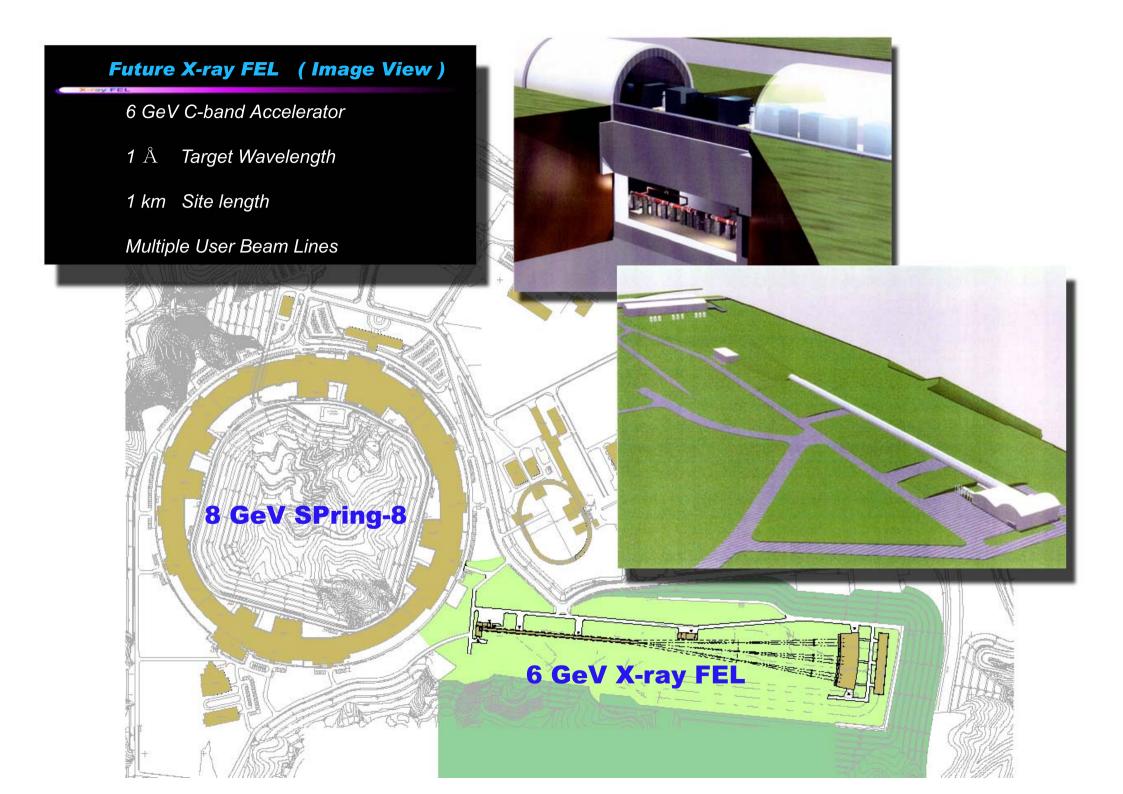
K. Togawa

SPring-8 / RIKEN Harima Institute

T. Shintake, H. Baba, T. Inagaki, K. Onoe, T. Tanaka SPring-8 / RIKEN Harima Institute

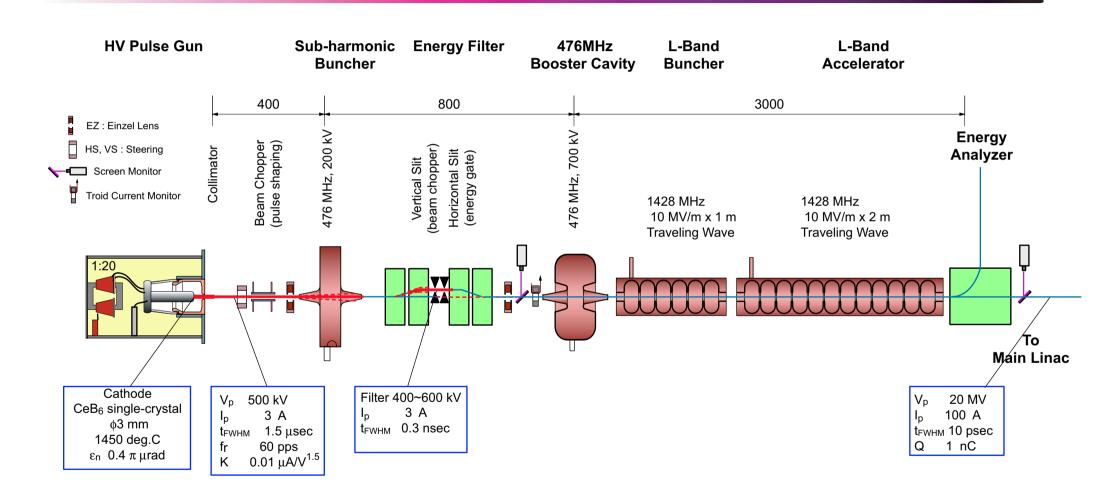
H. Matsumoto

High Energy Accelerator Research Organization (KEK)



Low Emittance Injector for SASE-FEL

X-ray FEL



CeB₆ Cathode Development

Choice of Cathode Material

X-FEL Requirements

Very Low emittance

$$\varepsilon_{n,rms} \leq 1\pi \ mm.mrad$$

High Beam Current at Gun

$$I_p \sim 3A$$

Thermal Emittance

$$\varepsilon_{n,rms} = \frac{r_c}{2} \sqrt{\frac{k_B T}{m_e c^2}}$$

Small Cathode

$$r_c \leq 2mm$$

$$T = 1000 \sim 1500^{\circ}C$$



High Emission Density

$$j_c \sim 50A/cm^2$$

Long Lifetime

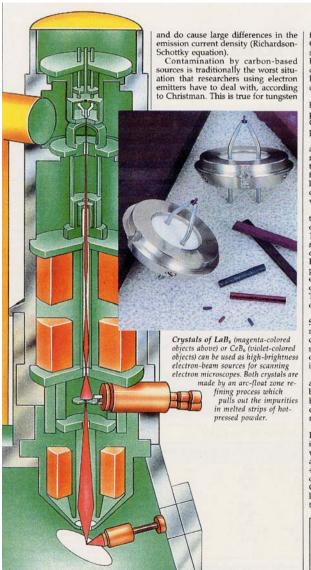
>10,000 hours

Rare-earth Hexaborides

LaB6 or CeB6

CeB6 (Cerium Hexaboride) Single-Crystal Cathode

CeB6 cathode is widely used in electron microscope !!



filament, LaB_e, and CeB_e emitters. Carbon contamination hurts the emission properties of thermionic emitters by causing the work function to increase dramatically, thus resulting in higher operating temperatures and increased material volatility.

Severe contamination on hexaboride thermionic emitters can completely turn them off. However, the CeB₆ emitters can recover more completely than can LaB₆ emitters.

When carbon contamination, for example, gets on a filament, the operator must turn the power control higher to get emission back. This raises the filament temperature and shortens its lifetime. CeB's higher tolerance to contamination, therefore, is more relevant than the close work function.

To compare their respective contamination resistances, CeB₆ and LaB₆ crystals were exposed to acetone at 1670 K. Thermionic emission for both materials decreased to less than 20% of their original levels after exposure. However, increasing the emitter temperature to 1825 K and increasing the emission current returned the CeB₆ crystal to its original emission value. The LaB₆ crystal returned to only 24% of its original value.

When CeB₆ cathodes are heated in SEM environments, surface contaminants on the crystals are more quickly desorbed. The emission current also stabilizes more quickly than for LaB₆ once the cathode has reached operating temperatures.

Other rare earth hexaboride materials, including praseodymium hexaboride and samarium hexaboride, have been investigated as thermionic emitters, but this research has been minimal, says Christman.

CeB_e cathodes can directly replace LaB_e cathodes without any changes in instrument operating parameters and with no changes in brightness or total available beam current. About 35% to 40% of all electron-beam instruments currently use LaB_e. For any of these, CeB_e could more than double emitter life and improve contamination resistance.



FEI Company

19500 NW Gibbs Drive, Suite 100 Beaverton, OR 97006-6907 (503) 690-1500 Fax (503) 690-1509

Properties

- Very flat surface (surface roughness <1 μm)
- Low workfunction (~2.4 eV)
- Long lifetime (>10,000 hours)
- Rapid recovery from contamination

Design parameter of SCSS cathode

Thermal Emittance

$$\varepsilon_{n,rms} = \frac{r}{2} \sqrt{\frac{k_B T}{m_e c^2}} = 0.4 \, \pi \, \text{mm mrad}$$

Cathode Radius r=1.5 mmTemperature $T=1450^{\circ}\text{C} (1723 \text{ K})$

Emission Current Density

Richardson-Dashman's Formula (Ideal Case)

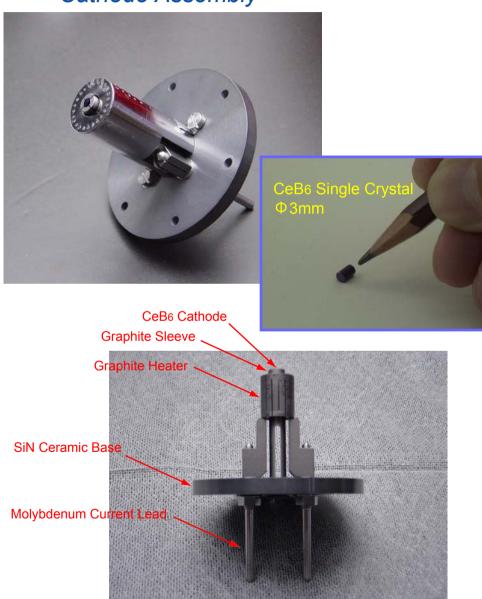
$$J = 120.4 \ T^2 \exp(-\phi'/k_BT) > 42 \ A/cm^2$$

Boltzmann's Constant $k_B = 8.617 \times 10^{-5} (eV/K)$

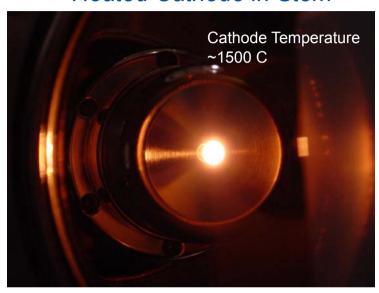
Effective Workfunction
$$\phi' = \phi - \frac{e}{2} \sqrt{\frac{eE}{\pi \epsilon_0}} \sim 2.3 \ (eV)$$

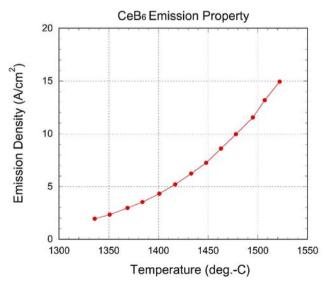
CeB6 Cathode Assembly (New Model)

Cathode Assembly



Heated Cathode in Stem

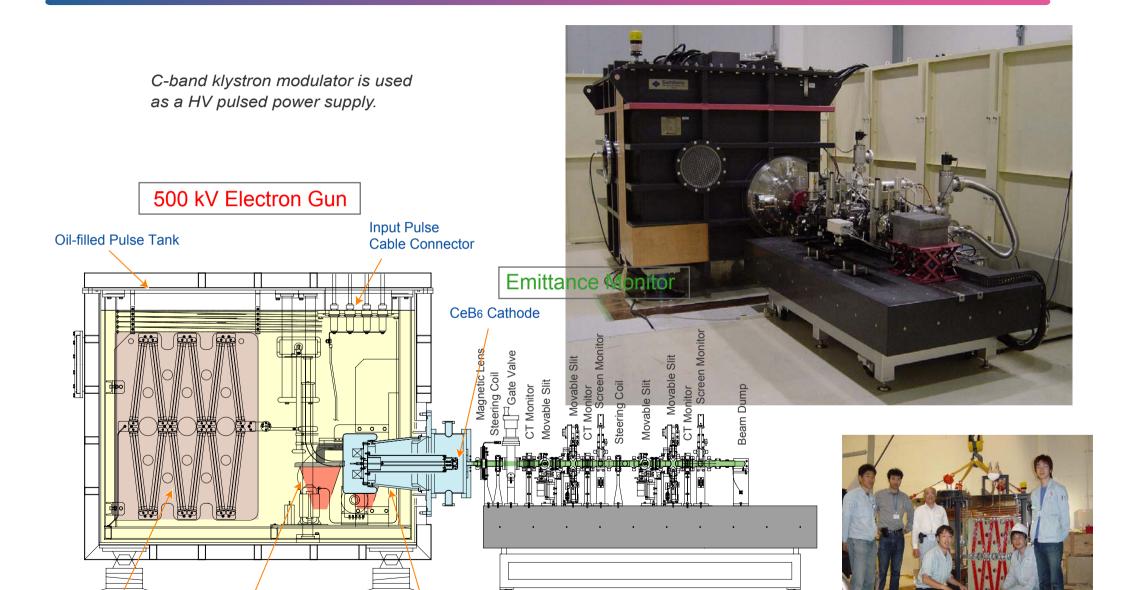




The gun voltage=500 kV Temperature was measured at the graphite sleeve by a radiation monitor.

500 kV Electron Gun

500 kV Electron Gun



1 m

HV Bushing

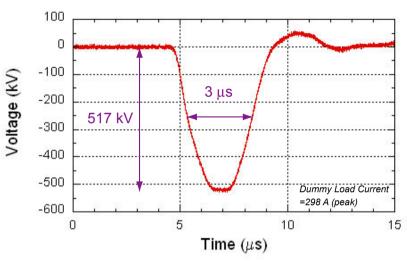
Pulse Transformer

Dummy Load

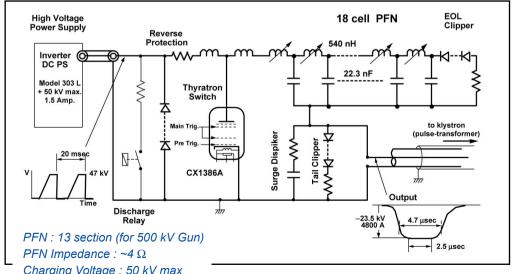
C-band Klystron Modulator

Same model of the C-band klystron modulator is used for the 500 kV electron gun.

Gun Pulse Waveform

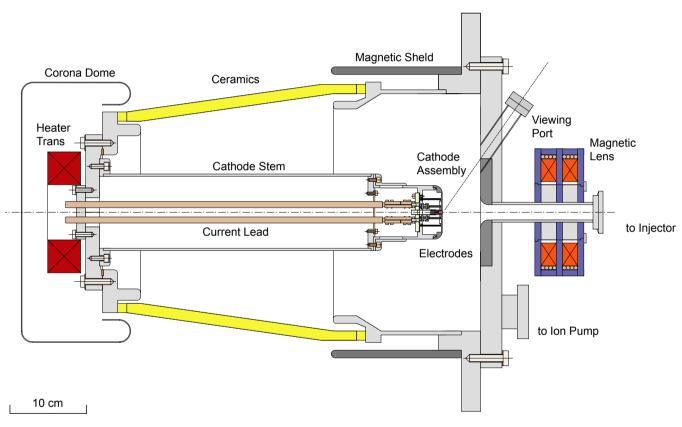


Circuit Diagram



Charging Voltage: 50 kV max Max. Repetition Rate: 60 pps

500 kV Electron Gun Chamber





Conceptual Design (2001)

500 keV Beam Production



Schottky Effect Droop of CT Monotor Space Charge Limit Sleeve Temperature 1533 deg.C 0 1485 deg.C - 1437 deg. C Beam Current - 1336 deg.C Gun Voltage (kV) Beam Current (A) -100 (CT Monitor) Space Charge Beam Current (A) Limited Region Temperature Limited Region -200 0.5 -300 Gun Voltage -400 (CVD Monitor)

6

7

8

~1 ns part will cut out from the flattop by a beam deflector, and be used for the SCSS accelerator.

Time (µs)

2

-500

0

We operate the gun in temperature limited region to reduce emittance growth due to space charge.

200

300

Gun Voltage (kV)

400

500

100

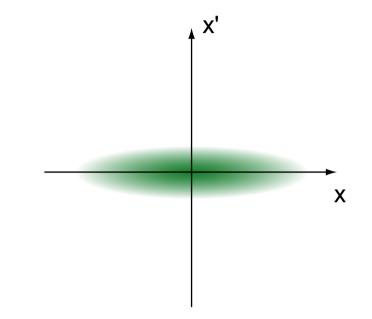
I-V Curve

Emittance Measurement

Normalized rms Emittance

Definition

$$\varepsilon_{n,rms} = \frac{1}{m_0 c} \sqrt{\langle x^2 \rangle \langle p_x^2 \rangle - \langle x \cdot p_x \rangle^2} \\
= \beta \gamma \sqrt{\langle x^2 \rangle \langle x'^2 \rangle - \langle x \cdot x' \rangle^2}$$



unit : π mm.mrad

$$\langle x^{2} \rangle = \frac{\iint x^{2}i(x, x')dxdx'}{\iint i(x, x')dxdx'}$$
$$\langle x'^{2} \rangle = \frac{\iint x'^{2}i(x, x')dxdx'}{\iint i(x, x')dxdx'}$$
$$\langle x \cdot x' \rangle = \frac{\iint x \cdot x'i(x, x')dxdx'}{\iint i(x, x')dxdx'}$$

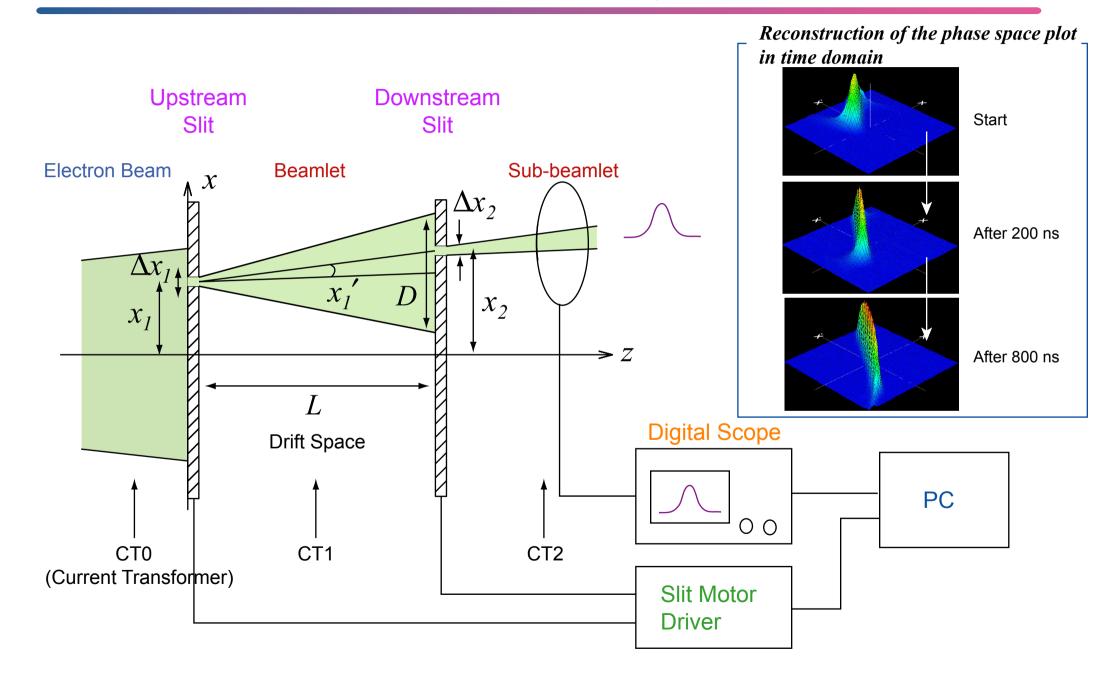
$$r_c$$
 T Cathode

$$\varepsilon_{n,rms} = \frac{r_c}{2} \sqrt{\frac{k_B T}{m_0 c^2}}$$

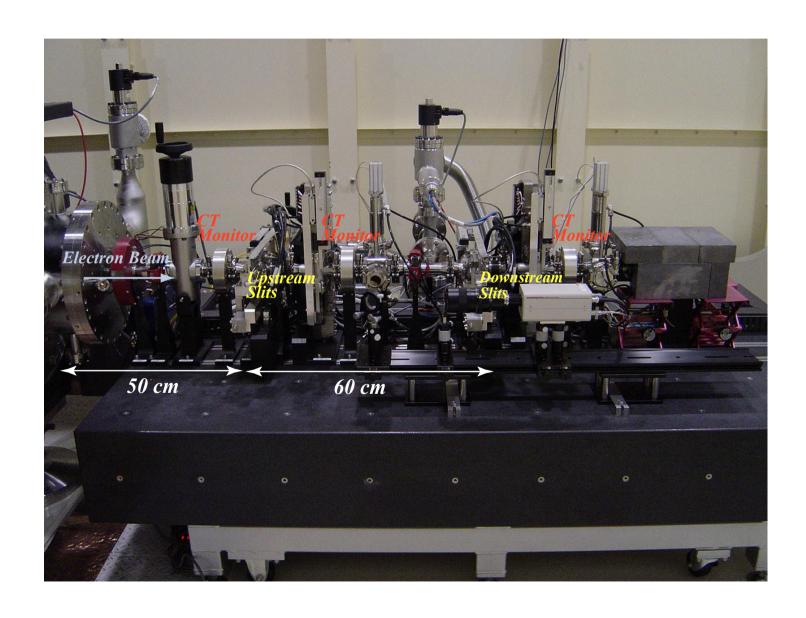
 $=0.4 \pi$ mm.mrad

(r_c = 1.5 mm, T = 1723 K (1450°C))

Emittance Measurement by Double-slits

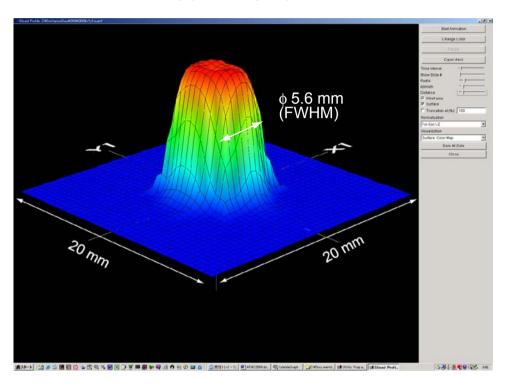


Emittance Monitor

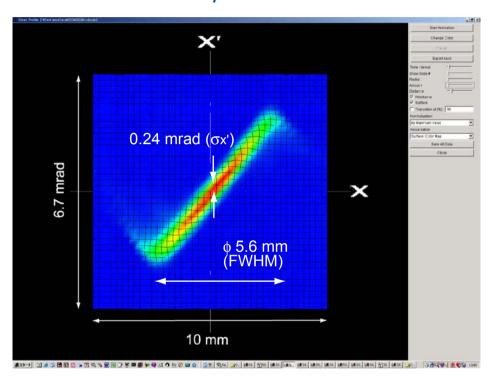


Emittance of 500 keV Beam

Beam Profile



Phase Space Profile



Beam Energy : 500 keV Peak Current : 1.0 A

Pulse Width : 3 μs

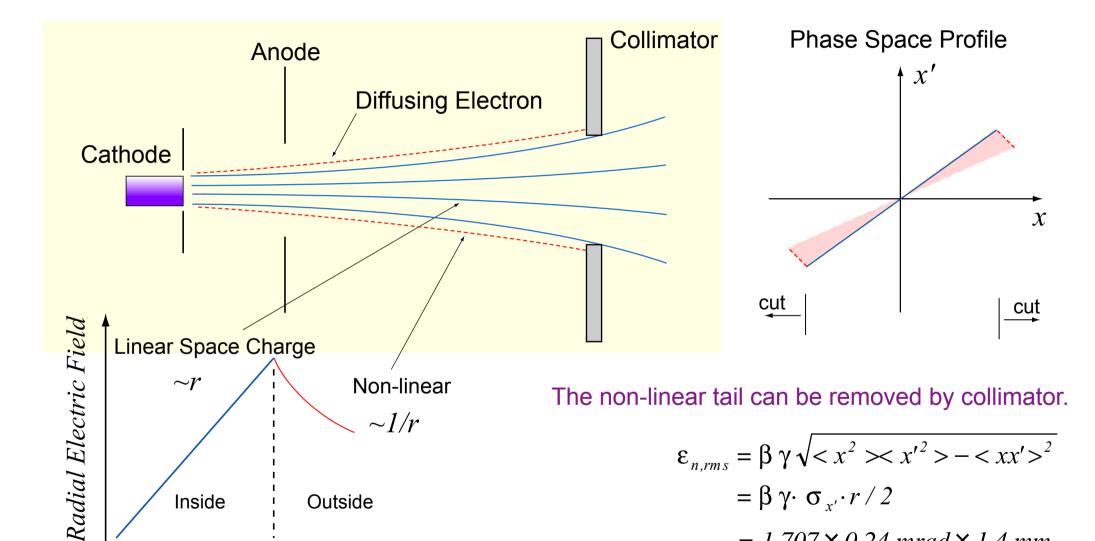
Emittance (En,rms)

Requirement : 2π mm.mrad @Undulator

Experiment : 1.1π mm.mrad @Gun (preliminary)

 $\varepsilon_{n,rms} = \beta \gamma \sqrt{\langle x^2 \rangle \langle x'^2 \rangle - \langle xx' \rangle^2}$

Emittance with Thermal Diffusion and Non-linear Space Charge



 $= \beta \gamma \cdot \sigma_{r'} \cdot r / 2$ Inside Outside $= 1.707 \times 0.24 \, mrad \times 1.4 \, mm$ $= 0.6 \pi mm.mrad (expected)$ Electrons diffuse to the outside by thermal motion.

Non-linear space charge force breaks emittance.

Summary

1) We have succeeded in producing a 500 keV, 1 A beam from the CeB6 gun.

2) Measured emittance was $\sim 1\pi$ mm mrad.

3) In 2004, we will install a beam deflector and a buncher system, and measure the bunched beam emittance.